

### **Atomic-scale engineering of electrodes for single-molecule contacts**



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#### TNT2011 Tenerife, November 23, 2011

Drain

J. C. Scott, J. Vac. Sci. Technol. A 21, 521–531 (2003)

Cathode

Thermal population

 $E_{\varepsilon}$ 

**Extended** states

# The problem of electronic contacts

Transport of charge through a conducting material

• intrinsic ability of the material to conduct current

**LUMO** 

Localized states

Electron transport layer

 $E_{\epsilon} + \phi_{c}$ 

• charge injection efficiency at the contacts

Organic materials (OPC, OLED, OFET)

 $(a)$ 

 $(b)$ 

 $(c)$ 

Organic layer(s)

Ground plane

Top electrode

Organic layer(s)

**Bottom electrode** 

Organic layer Gate dielectric Gate electrode

Source

#### Carbon nanotubes







glass

glass

bare MWNT

**Ti/Au Contact** 

 $1.5 \mu m$ 

Pad





# Valid down to a single molecule?



Y. Xue and M. A. Ratner, PRB 68, 115407 (2003) K. H. Müller, PRB 73, 045403 (2006) S. Quek et al., Nano Lett. 7, 3477 (2007) M. Paulsson et al., Nano Lett. 9, 117 (2009)

# First-principles methods: DFT+NEGF



Big and complex systems:

- Coupling to electrodes
- Chemical bonding
- Interface geometry

#### Density Functional Theory (DFT):

- Handles 100-1000 atoms and their chemistry
- No fitting parameters
- Vibrational frequencies and modes from ground state

#### Nonequilibrium Green's functions (NEGF):

- Open systems
- Finite currents
- Particle interactions in the scattering region

SIESTA: Soler, Artacho, Gale, García, Junquera, Ordejón, Sánchez-Portal, J. Phys.: Condens. Matter 14, 2745 (2002) TranSIESTA: Brandbyge, Mozos, Ordejón, Taylor, Stokbro, PRB 65, 165401 (2002)



# Contacting single molecules



S. Kubatkin et al., Nature 425, 698 (2003)





# Using STM to contact fullerene molecules



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13 MARCH 1995

#### Electronic Transparence of a Single  $C_{60}$  Molecule

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We report the first study of electrical contact with an individual molecule  $(C_{60})$ . Using a scanning tunneling microscope tip, the electrical current  $I$  flowing as a function of tip displacement  $s$  towards the molecule is investigated  $[I(s)]$  characteristics]. The tunneling current increases approximately exponentially with tip displacement in the tunnel regime, but this behavior changes significantly as contact is established. From the  $I(s)$  data and calculations for  $C_{60}$  we determine an apparent electrical resistance of 54.80 M $\Omega$  for the junction at "tip contact." In the Landauer formalism, this value is a measurement of the electronic transparence  $2.35 \times 10^{-4}$  of the molecule under the tip.



# Controlled contact with the STM

**Dipc** 



N. Néel, J. Kröger, L. Limot, TF, M. Brandbyge, R. Berndt, PRL 98, 065502 (2007)

## Controlled contact with the STM

**Dipc** 



N. Néel, J. Kröger, L. Limot, TF, M. Brandbyge, R. Berndt, PRL 98, 065502 (2007)

# Attaching a  $C_{60}$  molecule to the STM tip









Experimental procedure:

- 1. Position metallic tip over target  $C_{60}$  molecule
- 2. Set constant current (100nA)
- 3. Ramp voltage from 2V to 0.01V and back
- 4.  $C_{60}$  tips characterized by "reverse" imaging

Au adatoms on Au(111)



#### Cluster of Au adatoms

Hole after target  $C_{60}$  molecule was transferred to the tip

G. Schull, TF, M. Brandbyge, R. Berndt, PRL 103, 206803 (2009)

# Contact experiments with  $C_{60}$  tips

#### Model structures for the three experiments:

Three experiments:

- 1. Metal tip to C60 molecule
- 2. C60 tip to flat Cu(111) surface
- 3. C60 tip to C60 molecule

What is the (maximum) conductance of these junctions?

$$
G^{(2)} > G^{(1)} > G^{(3)}
$$

This tells us that:

- The conductance through a single  $C_{60}$  molecule is affected by the number of atomic contacts
- The conductance of a pair of  $C_{60}$ molecules is much lower than for for single molecules



Theory (symbols) allows to calibrate absolute distances of the experimental data (full lines)





How does the conductance of a single  $C_{60}$  molecule depend on the number of contacting atoms?

#### **Dipc** Atomic-scale engineering of the contacts

#### Preparing Cu adatoms on Cu(111)



How does the conductance of a single  $C_{60}$  molecule depend on the number of contacting atoms?

#### Experimental conductance traces



than an order of magnitude

# Simulating contact geometries







Theory: Two different electrode separations Experiment: Clusters approached with 6 different tips



- Flat surface defined as  $N = 16$
- Good agreement between theory and experiment
- $\cdot$  G(N) scales approximately linearly with N

Theory: Two different electrode separations Experiment: Clusters approached with 6 different tips



Theory: Two different electrode separations Experiment: Clusters approached with 6 different tips

- Good agreement between theory and experiment
- $\cdot$  G(N)/N grows with N for small N
- Maximum at  $N = 5$  marks crossover between cluster-size limited ("bad contact") and molecule-limited ("good contact") transport regimes



# Origin of the super-linear increase?

 $\mathcal{C}$ 

$$
T(E) = Tr[\Gamma_{\text{tip}}(E) G(E) \Gamma_{\text{cuN}}(E) G^{\dagger}(E)]
$$

 $\Gamma_{\text{CUN}}(E) \sim V^2$  DOS(E);  $G(E) = [E - H + i\Gamma_{\text{tip}}/2 + i\Gamma_{\text{CUN}}/2]^{-1}$ 



TNT2011 Tenerife, November 23, 2011 G. Schull, TF, A. Arnau, D. Sanchez-Portal, R. Berndt, Nature Nanotechnol. 6, 23 (2011)

#### **Dipc** Visualization of transmission eigenchannels



TNT2011 Tenerife, November 23, 2011 G. Schull, TF, A. Arnau, D. Sanchez-Portal, R. Berndt, Nature Nanotechnol. 6, 23 (2011)

# Conclusions and outlook

- Demonstration of atomic-scale engineering of contact interfaces
- Contact geometry strongly influences on electronic conduction
- Conductance of a single  $C_{60}$  junction varies up to a factor 20
- "Good" and "bad" contact regimes identified for  $C_{60}$  (crossover  $N \sim 5$ )
- DFT+NEGF simulations reproduces quantitatively exp. results
- Theory provides insight into mechanisms controlling transport
- Molecular orientation? Contact position?



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